



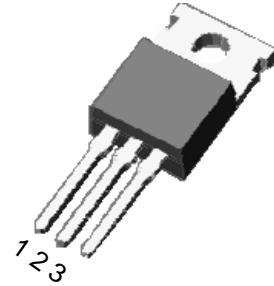
# MJE13008APG, MJE13009APG

NPN Silicon Transistor

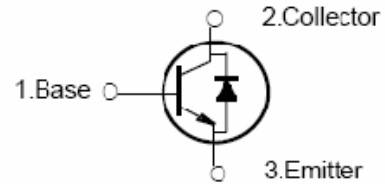
PIN Connection TO-220

## High Voltage Switch Mode Application

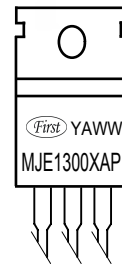
- High Speed Switching
- Suitable for Switching Regulator and Motor Control



### Symbol



### Marking Diagram



- Y            = Year
- A            = Assembly Location
- WW         = Work Week
- MJE1300XAP = Specific Device Code

## Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage		
	: MJE13008AP	600	V
	: MJE13009AP	700	V
$V_{CEO}$	Collector-Emitter Voltage		
	: MJE13008AP	300	V
	: MJE13009AP	400	V
$V_{EBO}$	Emitter-Base Voltage	9	V
$I_C$	Collector Current (DC)	12	A
$I_{CP}$	Collector Current (Pulse)	24	A
$I_B$	Base Current	6	A
$P_C$	Collector Dissipation ( $T_C=25^\circ\text{C}$ )	100	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$



# MJE13008APG, MJE13009APG

## Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage : MJE13008AP : MJE13009AP	$I_C = 10\text{mA}, I_B = 0$	300 400			V V
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 9\text{V}, I_C = 0$			1	mA
$h_{FE}$	* DC Current Gain	$V_{CE} = 5\text{V}, I_C = 5\text{A}$ $V_{CE} = 5\text{V}, I_C = 8\text{A}$	8 6		40 30	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 5\text{A}, I_B = 1\text{A}$ $I_C = 8\text{A}, I_B = 1.6\text{A}$ $I_C = 12\text{A}, I_B = 3\text{A}$			1 1.5 3	V V V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = 5\text{A}, I_B = 1\text{A}$ $I_C = 8\text{A}, I_B = 1.6\text{A}$			1.2 1.6	V V
$C_{ob}$	Output Capacitance	$V_{CB} = 10\text{V}, f = 0.1\text{MHz}$		180		pF
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 0.5\text{A}$	4			MHz
$t_{ON}$	Turn On Time	$V_{CC} = 125\text{V}, I_C = 8\text{A}$ $I_{B1} = - I_{B2} = 1.6\text{A}$ $R_L = 15,6\Omega$			1.1	$\mu\text{s}$
$t_{STG}$	Storage Time				3	$\mu\text{s}$
$t_F$	Fall Time				0.7	$\mu\text{s}$

\* Pulse test:  $PW \leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$

## Typical Characteristics

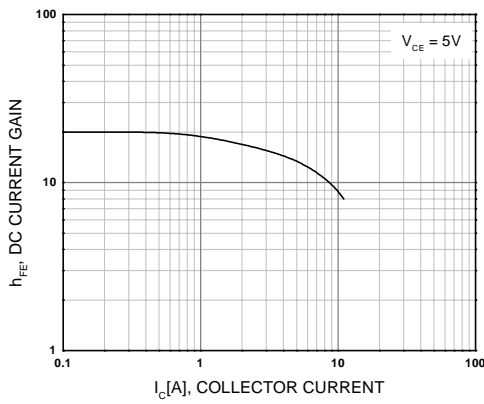


Figure 1. DC current Gain

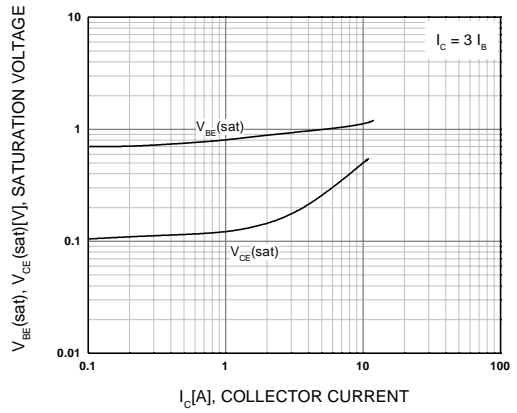


Figure 2. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

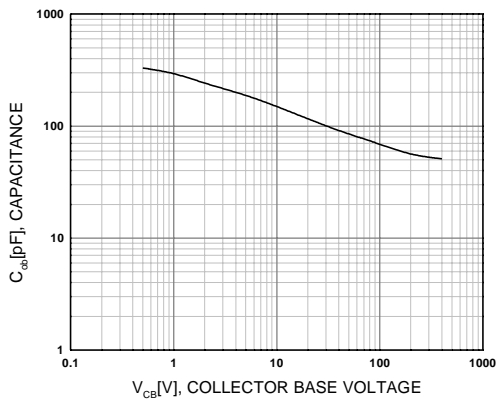


Figure 3. Collector Output Capacitance

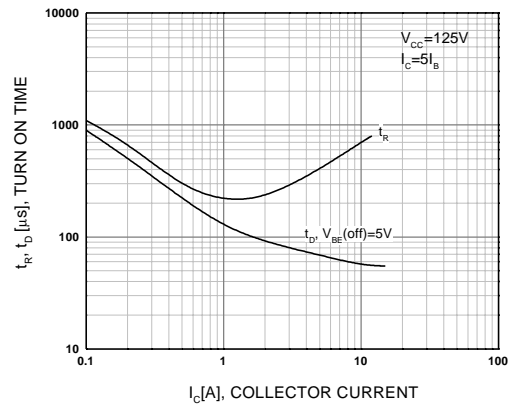


Figure 4. Turn On Time

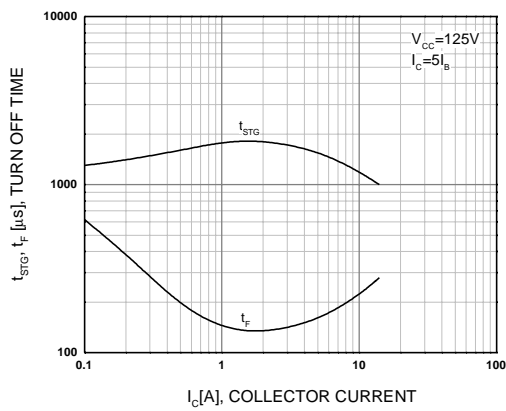


Figure 5. Turn Off Time

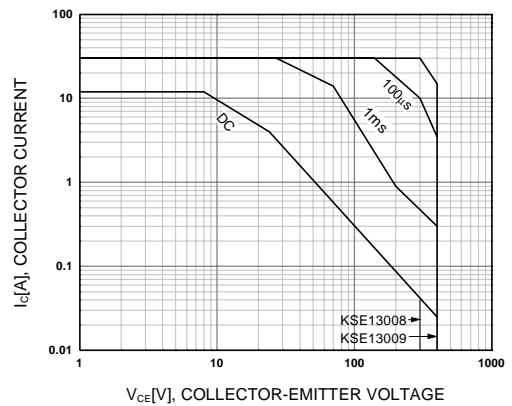


Figure 6. Safe Operating Area

## Typical Characteristics (Continued)

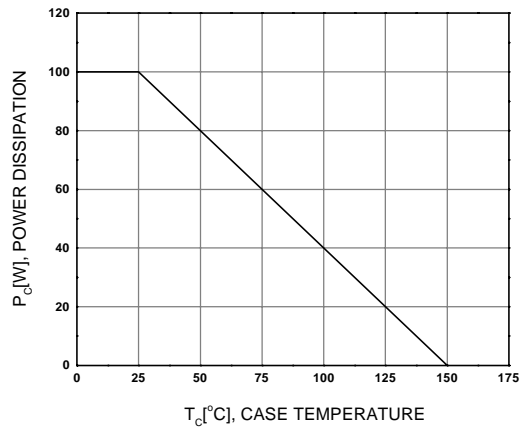
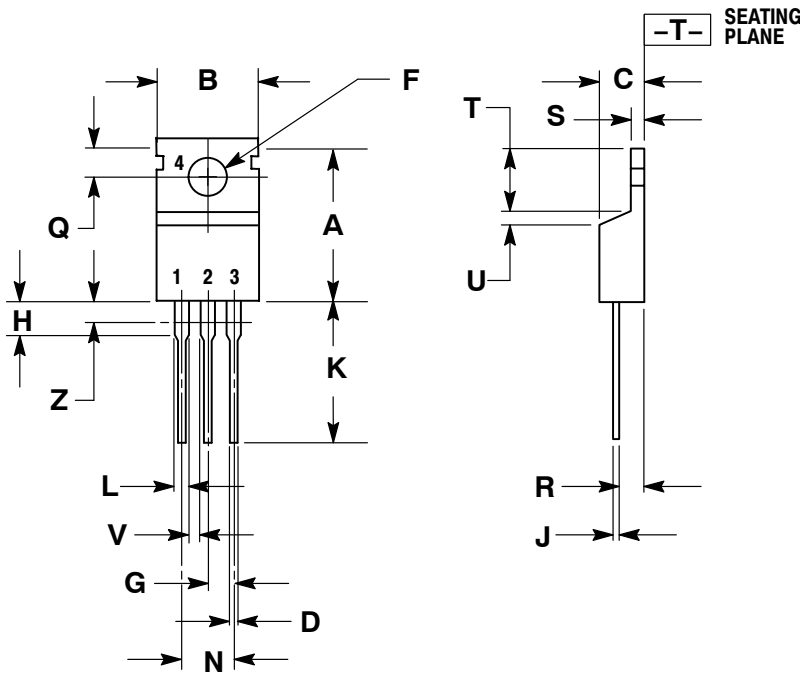


Figure 7. DC current Gain

## Package Dimension

### TO-220



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 6:

- PIN 1. ANODE  
 2. CATHODE  
 3. ANODE  
 4. CATHODE